



December 1990

F100331

Low Power Triple D Flip-Flop

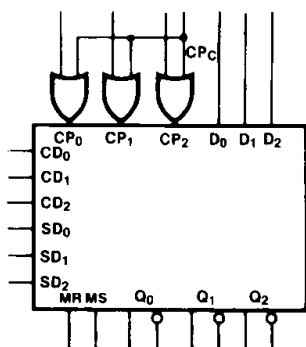
General Description

The F100331 contains three D-type, edge-triggered master/slave flip-flops with true and complement outputs, a Common Clock (CP_C), and Master Set (MS) and Master Reset (MR) inputs. Each flip-flop has individual Clock (CP_n), Direct Set (SD_n) and Direct Clear (CD_n) inputs. Data enters a master when both CP_n and CP_C are LOW and transfers to a slave when CP_n or CP_C (or both) go HIGH. The Master Set, Master Reset and individual CD_n and SD_n inputs override the Clock inputs. All inputs have 50 k Ω pull-down resistors.

Features

- 35% power reduction of the F100131
- 2000V ESD protection
- Pin/function compatible with F100131
- Voltage compensated operating range = -4.2V to -5.7V

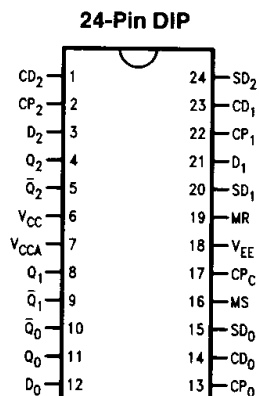
Logic Symbol



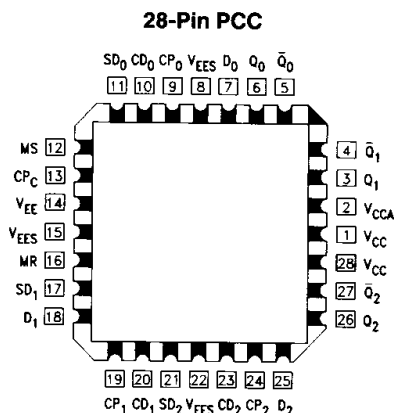
TL/F/10262-1

Pin Names	Description
CP_0 - CP_2	Individual Clock Inputs
CP_C	Common Clock Input
D_0 - D_2	Data Inputs
CD_0 - CD_2	Individual Direct Clear Inputs
SD_n	Individual Direct Set Inputs
MR	Master Reset Input
MS	Master Set Input
Q_0 - Q_2	Data Outputs
$\bar{Q}_0$ - $\bar{Q}_2$	Complementary Data Outputs

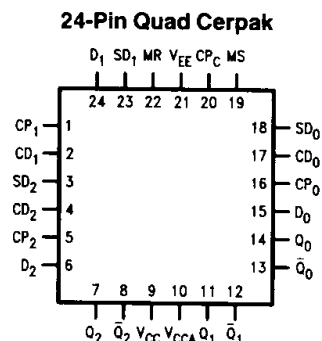
Connection Diagrams



TL/F/10262-2



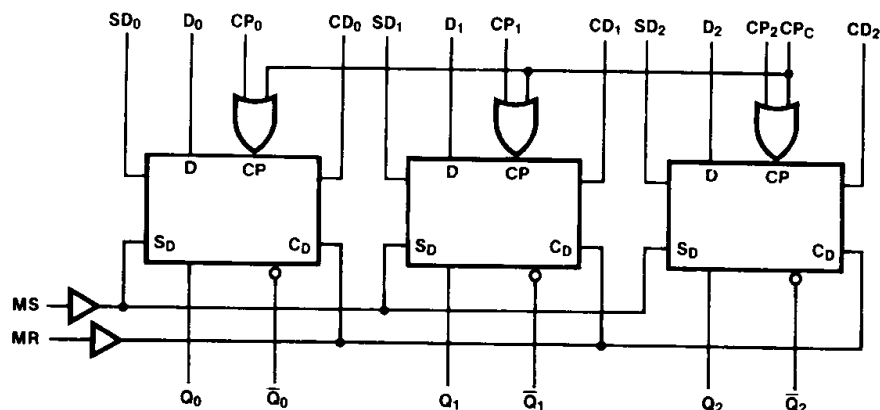
TL/F/10262-4



TL/F/10262-3

F100331 Low Power Triple D Flip-Flop

Logic Diagram



TL/F/10262-5

Truth Tables (Each Flip-Flop)

Synchronous Operation

Inputs					Outputs
D_n	CP_n	CP_c	MS SD_n	MR CD_n	$Q_n(t + 1)$
L	↗	L	L	L	L
H	↗	L	L	L	H
L	L	↗	L	L	L
H	L	↗	L	L	H
X	L	L	L	L	$Q_n(t)$
X	H	X	L	L	$Q_n(t)$
X	X	H	L	L	$Q_n(t)$

Asynchronous Operation

Inputs					Outputs
D_n	CP_n	CP_c	MS SD_n	MR CD_n	$Q_n(t + 1)$
X	X	X	H	L	H
X	X	X	L	H	L
X	X	X	H	H	U

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

U = Undefined

t = Time before CP Positive Transition

t + 1 = Time after CP Positive Transition

↗ = LOW to HIGH Transition

Absolute Maximum Ratings

Above which the useful life may be impaired (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature (T_{STG}) -65°C to $+150^{\circ}\text{C}$

Maximum Junction Temperature (T_J)

Ceramic $+175^{\circ}\text{C}$

Plastic $+150^{\circ}\text{C}$

Pin Potential to

Ground Pin (V_{EE}) -7.0V to $+0.5\text{V}$

Input Voltage (DC) V_{EE} to $+0.5\text{V}$

Output Current

(DC Output HIGH)

-50 mA

ESD (Note 2)

$\leq 2000\text{V}$

Recommended Operating Conditions

Case Temperature (T_C)

Commercial

0°C to $+85^{\circ}\text{C}$

Military

-55°C to $+125^{\circ}\text{C}$

Supply Voltage (V_{EE})

Commercial

-5.7V to -4.2V

Military

-5.7V to -4.2V

Commercial Version

DC Electrical Characteristics

$V_{EE} = -4.2\text{V}$ to -5.7V , $V_{CC} = V_{CCA} = \text{GND}$, $T_C = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ (Note 3)

Symbol	Parameter	Min	Typ	Max	Units	Conditions	
V _{OH}	Output HIGH Voltage	−1025	−955	−870	mV	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to −2.0V
V _{OL}	Output LOW Voltage	−1830	−1705	−1620	mV		
V _{OHC}	Output HIGH Voltage	−1035			mV	V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to −2.0V
V _{OLC}	Output LOW Voltage	−1610			mV		
V _{IH}	Input HIGH Voltage	−1165		−870	mV	Guaranteed HIGH Signal for All Inputs	
V _{IL}	Input LOW Voltage	−1830		−1475	mV	Guaranteed LOW Signal for All Inputs	
I _{IL}	Input LOW Current	0.5			μA	V _{IN} = V _{IL} (Min)	
I _{IH}	Input HIGH Current			240	μA	V _{IN} = V _{IH} (Max)	
I _{EE}	Power Supply Current	−122		−65	mA	Inputs Open	

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: ESD testing conforms to MIL-STD-883, Method 3015.

Note 3: The specified limits represent the "worst case" value for the parameter. Since these values normally occur at the temperature extremes, additional noise immunity and guardbanding can be achieved by decreasing the allowable system operating ranges. Conditions for testing shown in the tables are chosen to guarantee operate under "worst case" conditions.

Commercial Version (Continued)

Ceramic Dual-In-Line Package AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	T _C = 0°C		T _C = +25°C		T _C = +85°C		Units	Conditions		
		Min	Max	Min	Max	Min	Max				
f _{max}	Toggle Frequency	375		375		375		MHz	Figures 2 and 3		
t _{PLH} t _{PHL}	Propagation Delay CP _C to Output	0.75	2.00	0.75	2.00	0.75	2.00	ns	Figures 1 and 3		
t _{PLH} t _{PHL}	Propagation Delay CP _n to Output	0.75	2.00	0.75	2.00	0.75	2.00	ns			
t _{PLH} t _{PHL}	Propagation Delay CD _n , SD _n to Output	0.70	1.70	0.70	1.70	0.70	1.80	ns	CP _n , CP _C = L	Figures 1 and 4	
t _{PLH} t _{PHL}		0.70	2.00	0.70	2.00	0.70	2.00		CP _n , CP _C = H		
t _{PLH} t _{PHL}	Propagation Delay MS, MR to Output	1.10	2.60	1.10	2.60	1.10	2.60	ns	CP _n , CP _C = L		
t _{PLH} t _{PHL}		1.10	2.80	1.10	2.80	1.10	2.80		CP _n , CP _C = H		
t _{TLH} t _{THL}	Transition Time 20% to 80%, 80% to 20%	0.35	1.30	0.35	1.30	0.35	1.30	ns	Figures 1, 3 and 4		
t _s	Setup Time D _n	0.40		0.40		0.40		ns	Figure 5		
	CD _n , SD _n (Release Time)	1.30		1.30		1.30			Figure 4		
	MS, MR (Release Time)	2.30		2.30		2.30					
t _h	Hold Time D _n	1.00		1.00		1.00		ns	Figure 5		
t _{pw(H)}	Pulse Width HIGH CP _n , CP _C , CD _n , SD _n , MR, MS	2.00		2.00		2.00		ns	Figures 3 and 4		

PCC and Cerpak AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	T _C = 0°C		T _C = +25°C		T _C = +85°C		Units	Conditions	
		Min	Max	Min	Max	Min	Max			
f _{max}	Toggle Frequency	400		400		400		MHz	Figures 2 and 3	
t _{PLH} t _{PHL}	Propagation Delay CP _C to Output	0.75	1.80	0.75	1.80	0.75	1.80	ns	Figures 1 and 3	
t _{PLH} t _{PHL}	Propagation Delay CP _n to Output	0.75	1.80	0.75	1.80	0.75	1.80	ns		
t _{PLH} t _{PHL}	Propagation Delay CD _n , SD _n to Output	0.70	1.50	0.70	1.50	0.70	1.60	ns	CP _n , CP _C = L	Figures 1 and 4
t _{PLH} t _{PHL}		0.70	1.80	0.70	1.80	0.70	1.80		CP _n , CP _C = H	
t _{PLH} t _{PHL}	Propagation Delay MS, MR to Output	1.10	2.40	1.10	2.40	1.10	2.40	ns	CP _n , CP _C = L	
t _{PLH} t _{PHL}		1.10	2.60	1.10	2.60	1.10	2.60		CP _n , CP _C = H	
t _{TLH} t _{THL}	Transition Time 20% to 80%, 80% to 20%	0.35	1.10	0.35	1.10	0.35	1.10	ns	Figures 1, 3 and 4	
t _s	Setup Time							ns	Figure 5	
	D _n	0.30		0.30		0.30			Figure 4	
	CD _n , SD _n (Release Time)	1.20		1.20		1.20				
	MS, MR (Release Time)	2.20		2.20		2.20				
t _h	Hold Time D _n	0.90		0.90		0.90		ns	Figure 5	
t _{pw} (H)	Pulse Width HIGH CP _n , CP _C , CD _n , SD _n , MR, MS	2.00		2.00		2.00		ns	Figures 3 and 4	
t _{s G-G}	Skew, Gate to Gate	TBD		TBD		TBD		ps	PCC Only (Note 1)	

Note 1: Gate to gate skew is defined as the difference in propagation delays between each of the outputs.

Military Version—Preliminary DC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$, $T_C = -55^{\circ}C$ to $+125^{\circ}C$

Symbol	Parameter	Min	Max	Units	T _C	Conditions		Notes			
V _{OH}	Output HIGH Voltage	-1025	-870	mV	0°C to +125°C	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to -2.0V	1, 2, 3			
		-1085	-870	mV	-55°C						
V _{OL}	Output LOW Voltage	-1830	-1620	mV	0°C to +125°C				V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to -2.0V	1, 2, 3
		-1830	-1555	mV	-55°C						
V _{OHC}	Output HIGH Voltage	-1035		mV	0°C to +125°C	V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to -2.0V	1, 2, 3			
		-1085		mV	-55°C						
V _{OLC}	Output LOW Voltage		-1610	mV	0°C to +125°C				V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to -2.0V	1, 2, 3
			-1555	mV	-55°C						
V _{IH}	Input HIGH Voltage	-1165	-870	mV	-55°C to +125°C	Guaranteed HIGH Signal for all Inputs		1, 2, 3, 4			
V _{IL}	Input LOW Voltage	-1830	-1475	mV	-55°C to +125°C	Guaranteed LOW Signal for all Inputs		1, 2, 3, 4			
I _{IL}	Input LOW Current	0.50		μA	-55°C to +125°C	V _{EE} = -4.2V V _{IN} = V _{IL} (Min)		1, 2, 3			
I _{IH}	Input HIGH Current		240	μA	0°C to +125°C	V _{EE} = -5.7V V _{IN} = V _{IH} (Max)		1, 2, 3			
			340	μA	-55°C						
I _{EE}	Power Supply Current	-130	-50	mA	-55°C to +125°C	Inputs Open		1, 2, 3			

Note 1: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals $-55^{\circ}C$), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 2: Screen tested 100% on each device at $-55^{\circ}C$, $+25^{\circ}C$, and $+125^{\circ}C$, Subgroups, 1, 2, 3, 7 and 8.

Note 3: Sampled tested (Method 5005, Table I) on each manufactured lot at $-55^{\circ}C$, $+25^{\circ}C$, and $+125^{\circ}C$, Subgroups A1, 2, 3, 7 and 8.

Note 4: Guaranteed by applying specified input condition and testing V_{OH}/V_{OL} .

Military Version—Preliminary (Continued)

Ceramic Dual-In-Line Package AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = -55^\circ C$		$T_C = +25^\circ C$		$T_C = +125^\circ C$		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
f_{max}	Toggle Frequency	350		350		350		MHz	Figures 2 and 3	4
t_{PLH} t_{PHL}	Propagation Delay CP_C to Output	0.50	2.20	0.60	2.00	0.50	2.40	ns	Figures 1 and 3	1, 2, 3
t_{PLH} t_{PHL}	Propagation Delay CP_n to Output	0.50	2.20	0.60	2.00	0.50	2.40	ns		
t_{PLH} t_{PHL}	Propagation Delay CD_n , SD_n to Output	0.50	2.20	0.60	2.00	0.50	2.40	ns	CP_n , $CP_C = L$	
t_{PLH} t_{PHL}		0.50	2.40	0.60	2.10	0.50	2.50		CP_n , $CP_C = H$	
t_{PLH} t_{PHL}	Propagation Delay MS, MR to Output	0.70	2.70	0.80	2.60	0.80	2.90	ns	CP_n , $CP_C = L$	
t_{PLH} t_{PHL}		0.70	2.90	0.80	2.80	0.80	3.10		CP_n , $CP_C = H$	
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.20	1.40	0.20	1.40	0.20	1.40	ns	Figures 1, 3 and 4	
t_s	Setup Time D_n CD_n , SD_n (Release Time) MS, MR (Release Time)	1.00 1.50 2.50		0.80 1.30 2.30		0.90 1.60 2.50		ns	Figure 5 Figure 4	4
t_h	Hold Time D_n	1.50		1.30		1.60		ns	Figure 5	
$t_{pw(H)}$	Pulse Width HIGH CP_n , CP_C , CD_n , SD_n , MR, MS	2.00		2.00		2.00		ns	Figures 3 and 4	

Cerpak AC Electrical Characteristics

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = -55^\circ C$		$T_C = +25^\circ C$		$T_C = +125^\circ C$		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
f_{max}	Toggle Frequency	375		375		375		MHz	Figures 2 and 3	4
t_{PLH} t_{PHL}	Propagation Delay CP_C to Output	0.50	2.00	0.60	1.80	0.50	2.20	ns	Figures 1 and 3	1, 2, 3
t_{PLH} t_{PHL}	Propagation Delay CP_n to Output	0.50	2.00	0.60	1.80	0.50	2.20	ns		
t_{PLH} t_{PHL}	Propagation Delay CD_n , SD_n to Output	0.50	2.00	0.60	1.80	0.50	2.20	ns	CP_n , $CP_C = L$	
t_{PLH} t_{PHL}		0.50	2.20	0.60	1.90	0.50	2.30		CP_n , $CP_C = H$	
t_{PLH} t_{PHL}	Propagation Delay MS, MR to Output	0.70	2.50	0.80	2.40	0.80	2.70	ns	CP_n , $CP_C = L$	
t_{PLH} t_{PHL}		0.70	2.70	0.80	2.60	0.80	2.90		CP_n , $CP_C = H$	
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.20	1.20	0.20	1.20	0.20	1.20	ns	Figures 1, 3 and 4	

Note 1: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals $-55^\circ C$), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 2: Screen tested 100% on each device at $+25^\circ C$. Temperature only, Subgroup A9.

Note 3: Sample tested (Method 5005, Table I) on each Mfg. lot at $+25^\circ C$, Subgroup A9, and at $+125^\circ C$, and $-55^\circ C$ Temp., Subgroups A10 and A11.

Note 4: Not tested at $+25^\circ C$, $+125^\circ C$ and $-55^\circ C$ Temperature (design characterization data).

Cerpak AC Electrical Characteristics (Continued)

$V_{EE} = -4.2V$ to $-5.7V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = -55^\circ C$		$T_C = +25^\circ C$		$T_C = +125^\circ C$		Units	Conditions	Notes
		Min	Max	Min	Max	Min	Max			
t_s	Setup Time									
	D_n	0.90		0.70		0.80				
	CD_n , SD_n (Release Time)	1.40		1.20		1.50		ns	Figures 4 and 5	4
	MS, MR (Release Time)	2.40		2.20		2.40				
t_h	Hold Time D_n	1.40		1.20		1.50		ns	Figure 5	
$t_{pw(H)}$	Pulse Width HIGH CP_n , CP_C , CD_n , SD_n , MR, MS	2.00		2.00		2.00		ns	Figures 3 and 4	

Note 1: F100K 300 Series cold temperature testing is performed by temperature soaking (to guarantee junction temperature equals $-55^\circ C$), then testing immediately without allowing for the junction temperature to stabilize due to heat dissipation after power-up. This provides "cold start" specs which can be considered a worst case condition at cold temperatures.

Note 2: Screen tested 100% on each device at $+25^\circ C$. Temperature only, Subgroup A9.

Note 3: Sample tested (Method 5005, Table I) on each Mfg. lot at $+25^\circ C$, Subgroup A9, and at $+125^\circ C$, and $-55^\circ C$ Temp., Subgroups A10 and A11.

Note 4: Not tested at $+25^\circ C$, $+125^\circ C$ and $-55^\circ C$ Temperature (design characterization data).

Test Circuits

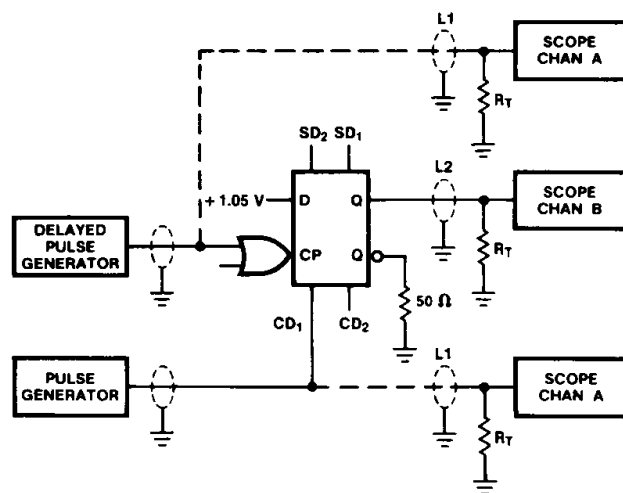


FIGURE 1. AC Test Circuit

TL/F/10262-6

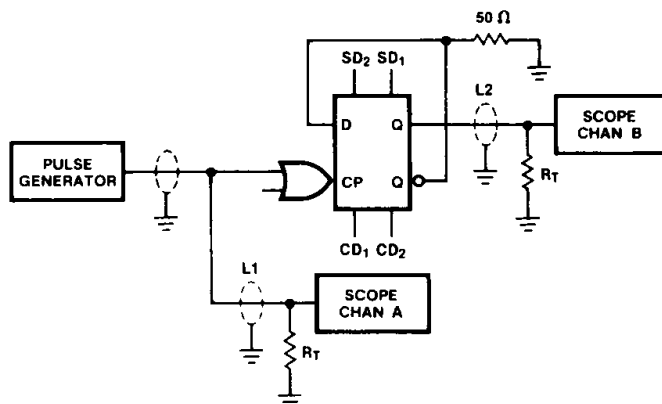


FIGURE 2. Toggle Frequency Test Circuit

TL/F/10262-7

Notes:

V_{CC} , $V_{CCA} = +2V$, $V_{EE} = -2.5V$

L1 and L2 = Equal length 50 ohm impedance lines

$R_T = 50\Omega$ terminator internal to scope

Decoupling 0.1 μF from GND to V_{CC} and V_{EE}

All unused outputs are loaded with 50 ohm to GND

C_L = Fixture and stray capacitance ≤ 3 pF

Switching Waveforms

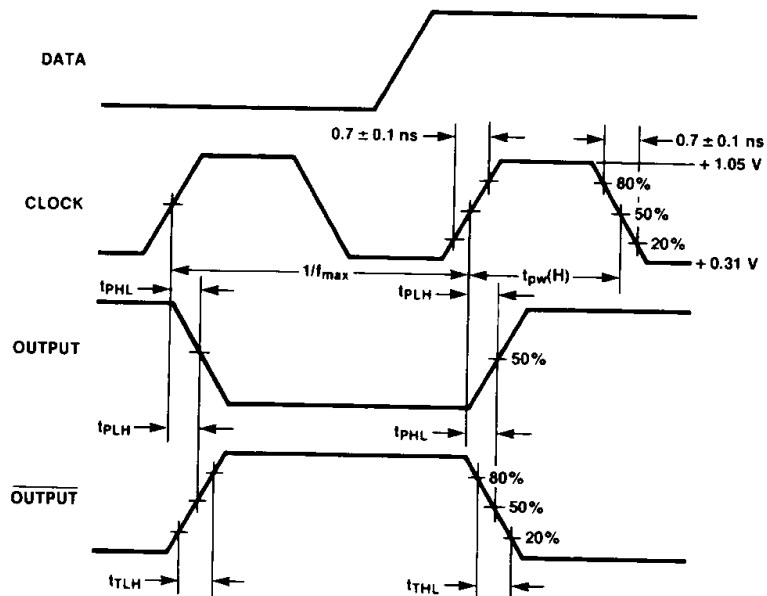


FIGURE 3. Propagation Delay (Clock) and Transition Times

TL/F/10262-8

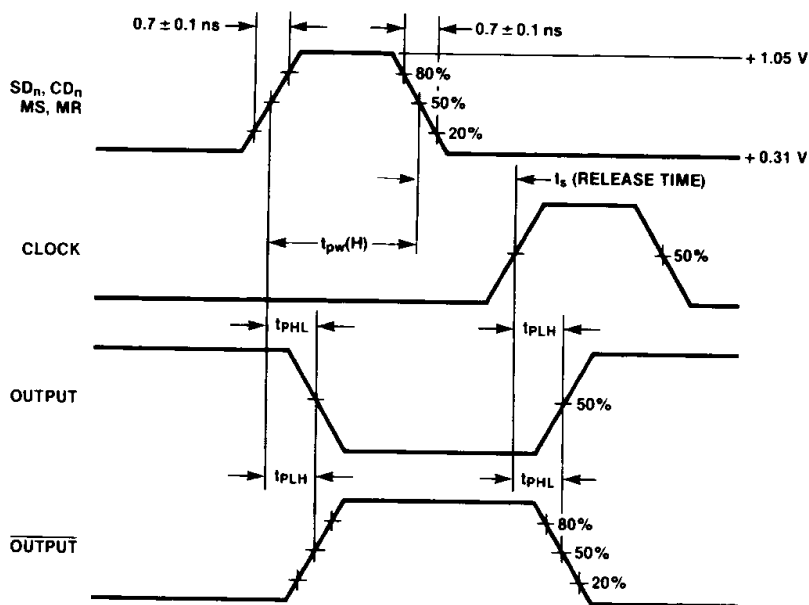


FIGURE 4. Propagation Delay (Resets)

TL/F/10262-9

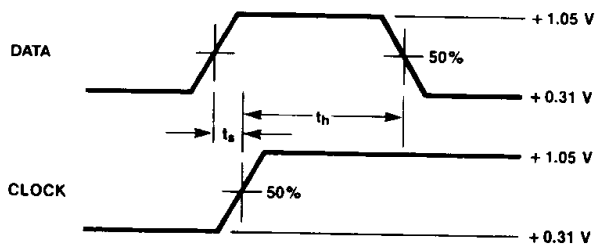


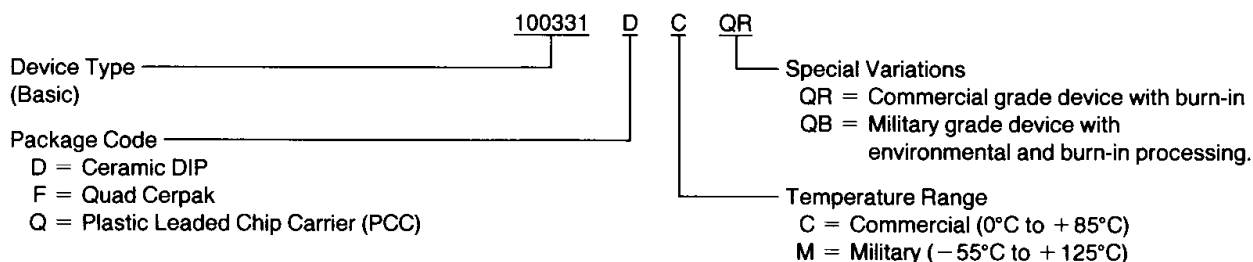
FIGURE 5. Data Setup and Hold Time

TL/F/10262-10

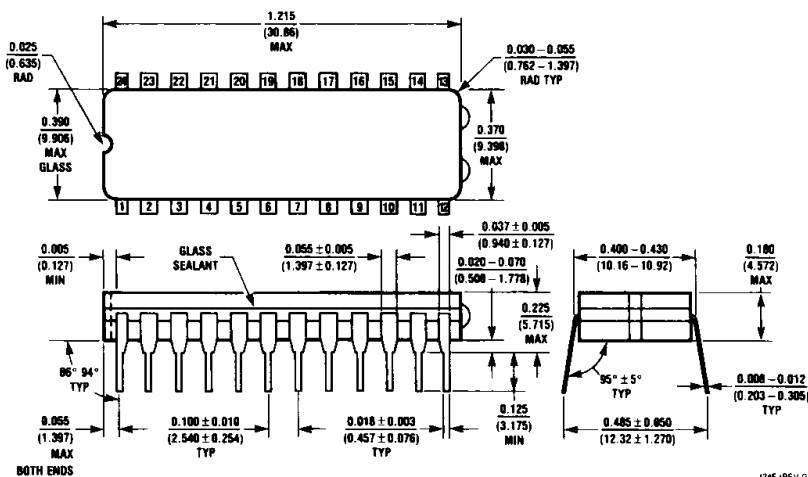
Note: t_s is the minimum time before the transition of the clock that information must be present at the data input.
Note: t_h is the minimum time after the transition of the clock that information must remain unchanged at the data input.

Ordering Information

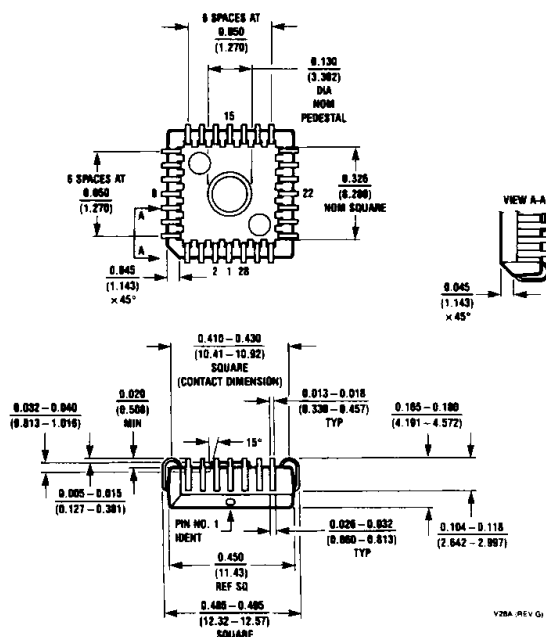
The device number is used to form part of a simplified purchasing code where a package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)



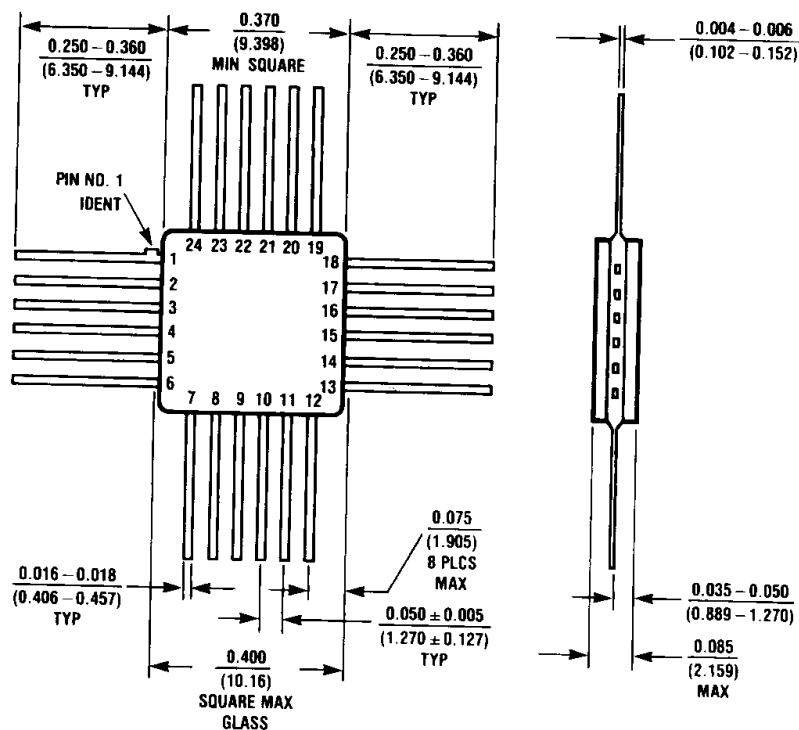
24-Lead Ceramic Dual-In-Line Package (0.400" Wide) (D)
NS Package Number J24E



28-Lead Plastic Chip Carrier (Q)
NS Package Number V28A

Physical Dimensions inches (millimeters) (Continued)

Lit. # 114912



**24-Lead Quad Cerpak (F)
NS Package Number W24B**

W24B (REV C)

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